查询UPA811T-T1-A供应商

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OUTLINE DIMENSIONS (Units in mm)

NPN SILICON HIGH FREQUENCY TRANSISTOR

UPA811T

FEATURES

- SMALL PACKAGE STYLE: 2 NE680 Die in a 2 mm x 1.25 mm package
- LOW NOISE FIGURE: NF = 1.9 dB TYP at 2 GHz
- HIGH GAIN: IS21El² = 7.5 dB TYP at 2 GHz
- EXCELLENT LOW VOLTAGE, LOW CURRENT PERFORMANCE

DESCRIPTION

NEC's UPA811T is two NPN high frequency silicon epitaxial transistors encapsulated in an ultra small 6 pin SMT package. Each transistor is independently mounted and easily configured for either dual transistor or cascode operation. The high ft, low voltage bias and small size make this device ideally suited for pager and other hand-held wireless applications.

ABSOLUTE MAXIMUM RATINGS ¹ (TA = 25°C)					
SYMBOLS	PARAMETERS	UNITS	RATINGS		
Vсво	Collector to Base Voltage	V	20		
VCEO	Collector to Emitter Voltage	V	10		
Vebo	Emitter to Base Voltage	V	1.5		
Ic	Collector Current	mA	35		
Рт	Total Power Dissipation 1 Die 2 Die	mW mW	110 200		
TJ	Junction Temperature	°C	150		
Тѕтс	Storage Temperature	°C	-65 to +150		

Note:

1. Operation in excess of any one of these parameters may result in permanent damage.

ELECTRICAL CHARACTERISTICS (TA = 25°C)

PART NUMBER PACKAGE OUTLINE			UPA811T S06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	ТҮР	MAX
Ісво	Collector Cutoff Current at VcB = 10 V, IE = 0	μΑ			1.0
Іево	Emitter Cutoff Current at VEB = 1 V, IC = 0	μΑ			1.0
hfe ¹	Forward Current Gain at Vce = 3 V, Ic = 5 mA		80	120	200
fτ	Gain Bandwidth at $V_{CE} = 3 \text{ V}$, $I_{C} = 5 \text{ mA}$	GHz	5.5	8.0	
Cre ²	Feedback Capacitance at VCB = 3 V, IE = 0, f = 1 MHz	pF		0.3	0.7
IS21El ²	Insertion Power Gain at VCE = 3 V, IC = 5 mA, f = 2 GHz	dB	5.5	7.5	
NF	Noise Figure at $V_{CE} = 3 V$, $I_C = 5 mA$, $f = 2 GHz$	dB		1.9	3.2

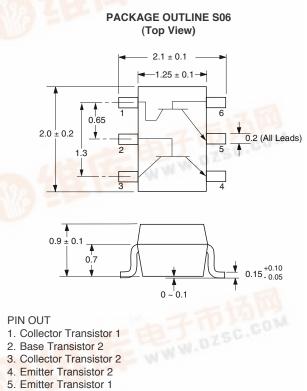
Notes:

df.dzsc.com

1.Pulsed measurement, pulse width \leq 350 μ s, duty cycle \leq 2 %.

2. The emitter terminal should be connected to the ground terminal of the 3 terminal capacitance bridge.

For Tape and Reel version use part number UPA811T-T1, 3K per reel.

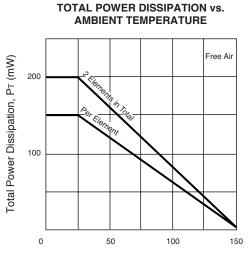


6. Base Transistor 1 Note:

Pin 3 is identified with a circle on the bottom of the package.

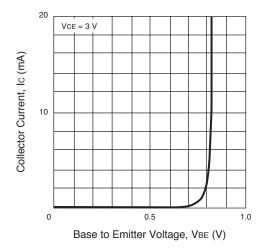


TYPICAL PERFORMANCE CURVES (TA = 25°C)

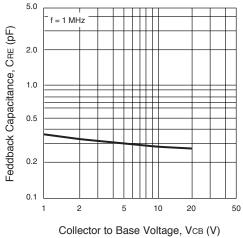


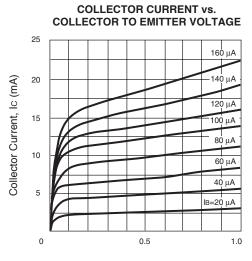
Ambient Temperature, TA (°C)

COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



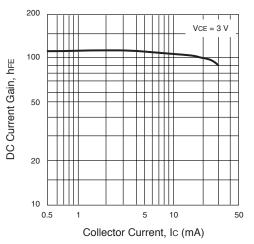




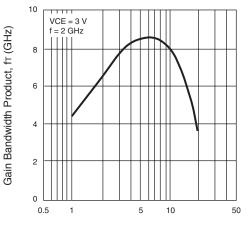


Collector to Emitter Voltage, VCE (V)

DC CURRENT GAIN vs. COLLECTOR CURRENT

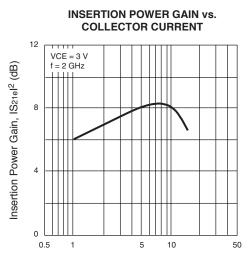


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

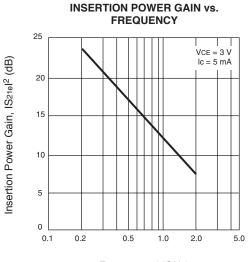


Collector Current, Ic (mA)

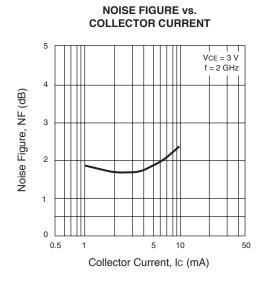
TYPICAL PERFORMANCE CURVES (TA = 25°C)



Collector Current, Ic (mA)



Frequency, f (GHz)



ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKAGING
UPA811T-T1-A	3000	Tape & Reel

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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CALIFORNIA EASTERN LABORATORIES • Headquarters • 4590 Patrick Henry Drive • Santa Clara, CA 95054-1817 • (408) 988-3500 • Telex 34-6393 • FAX (408) 988-0279 24-Hour Fax-On-Demand: 800-390-3232 (U.S. and Canada only) • Internet: http://WWW.CEL.COM

DATA SUBJECT TO CHANGE



4590 Patrick Henry Drive Santa Clara, CA 95054-1817 Telephone: (408) 919-2500 Facsimile: (408) 988-0279

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
РВВ	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

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